

#12 / 10-26-01  
Dade  
Amdt-A



520.37546X00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: TORII et al.  
Serial No.: 09/391,250  
Filed: September 7, 1999  
For: SEMICONDUCTOR DEVICE AND ITS FABRICATION METHOD  
Group: 2811  
Examiner: C. Nguyen

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OCT 25 2001  
1C 2800 MAIL ROOM

AMENDMENT

Assistant Commissioner  
for Patents  
Washington, D.C. 20231

October 22, 2001

Sir:

In response to the Office Action dated June 20, 2001, the period of response for which extension is requested by the attached Petition for Extension of Time, please amend the above-identified application as follows:

In the Title:

✓  
Please amend the title to read:

"Memory Structure With A Ferroelectric Capacitor And  
A Fabrication Method Thereof"